P-Channel Enhancement Mode Power MOSFET

DESCRIPTION

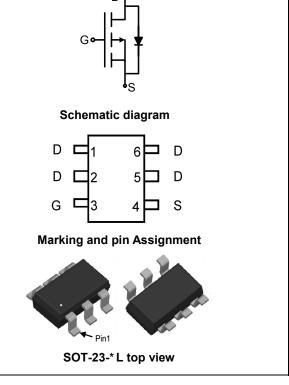
The HM6401 uses advanced trench technology to provide excellent $R_{DS(ON)}$, low gate charge and operation with gate voltages as low as 2.5V. This device is suitable for use as a load switch or in PWM applications.

GENERAL FEATURES

- V_{DS} = -30V,I_D = -5.0A
 - $R_{DS(ON)} < 130 m\Omega @ V_{GS} = -2.5 V$
 - $R_{DS(ON)} < 75m\Omega @ V_{GS}=-4.5V$
 - $R_{DS(ON)} < 65m\Omega @ V_{GS}=-10V$
- High Power and current handing capability
- Lead free product is acquired
- Surface Mount Package

Application

- ●PWM applications
- Load switch
- Power management



Package Marking And Ordering Information

| Device Marking | Device | Device Package | Reel Size | Tape width | Quantity |
|----------------|--------|----------------|-----------|------------|------------|
| 6401 | HM6401 | SOT-23-6L | Ø180mm | 8 mm | 3000 units |

Absolute Maximum Ratings (TA=25°C unless otherwise noted)

| Parameter | Symbol | Limit | Unit |
|--|-----------------|------------|------|
| Drain-Source Voltage | Vds | -30 | V |
| Gate-Source Voltage | V _{GS} | ±20 | V |
| Drain Current-Continuous | I _D | -5.0 | A |
| Drain Current-Pulsed (Note 1) | I _{DM} | -30 | A |
| Maximum Power Dissipation | PD | 1.2 | W |
| Operating Junction and Storage Temperature Range | TJ,TSTG | -55 To 150 | °C |

Thermal Characteristic

| Thermal Resistance, Junction-to-Ambient (Note 2) Reja 104 C/W | Thermal Resistance, Junction-to-Ambient (Note 2) | R _{0JA} | 104 | °C /W |
|---|--|------------------|-----|--------------|
|---|--|------------------|-----|--------------|

Electrical Characteristics (TA=25°C unless otherwise noted)

| Parameter | Symbol | Condition | Min | Тур | Max | Unit |
|---------------------------------|-------------------|--|-----|-----|-----|------|
| Off Characteristics | | | | | | |
| Drain-Source Breakdown Voltage | BV _{DSS} | V _{GS} =0V I _D =-250µA | -30 | | - | V |
| Zero Gate Voltage Drain Current | I _{DSS} | V _{DS} =-24V,V _{GS} =0V | - | - | -1 | μA |

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HM6401

| Gate-Body Leakage Current | I _{GSS} | V_{GS} =±20V, V_{DS} =0V | - | - | ±100 | nA |
|------------------------------------|---------------------|--|------|-----|------|----|
| On Characteristics (Note 3) | | | | | L | |
| Gate Threshold Voltage | V _{GS(th)} | $V_{DS}=V_{GS}$, $I_{D}=-250\mu A$ | -0.7 | -1 | -1.3 | V |
| | | V _{GS} =-10V, I _D =-4.2A | - | 50 | 55 | mΩ |
| Drain-Source On-State Resistance | R _{DS(ON)} | V _{GS} =-4.5V, I _D =-4A | - | 64 | 72 | mΩ |
| | | V _{GS} =-2.5V, I _D =-1A | | 95 | 120 | mΩ |
| Forward Transconductance | g fs | V _{DS} =-5V,I _D =-4.2A | - | 10 | - | S |
| Dynamic Characteristics (Note4) | · | | | | | |
| Input Capacitance | C _{lss} | (-15)()(-0)(| - | 950 | - | PF |
| Output Capacitance | C _{oss} | - V _{DS} =-15V,V _{GS} =0V, - F=1.0MHz | - | 115 | - | PF |
| Reverse Transfer Capacitance | C _{rss} | F = 1.0101112 | - | 75 | - | PF |
| Switching Characteristics (Note 4) | | | | | | |
| Turn-on Delay Time | t _{d(on)} | | - | 7 | - | nS |
| Turn-on Rise Time | tr | V _{DD} =-15V,I _D =-3.2A | - | 3 | - | nS |
| Turn-Off Delay Time | t _{d(off)} | V_{GS} =-10V,R _{GEN} =6 Ω | - | 30 | - | nS |
| Turn-Off Fall Time | t _f | | - | 12 | - | nS |
| Total Gate Charge | Qg | | - | 9.5 | - | nC |
| Gate-Source Charge | Q _{gs} | V _{DS} =-15V,I _D =-4A,V _{GS} =-4.5V | - | 2 | - | nC |
| Gate-Drain Charge | Q _{gd} | | - | 3 | - | nC |
| Drain-Source Diode Characteristics | · | · | | | - | |
| Diode Forward Voltage (Note 3) | V _{SD} | V _{GS} =0V,I _S =-1A | - | - | -1.2 | V |

Notes:

1. Repetitive Rating: Pulse width limited by maximum junction temperature.

2. Surface Mounted on FR4 Board, $t \le 10$ sec.

3. Pulse Test: Pulse Width \leq 300µs, Duty Cycle \leq 2%.

4. Guaranteed by design, not subject to production

TYPICAL ELECTRICAL AND THERMAL CHARACTERISTICS

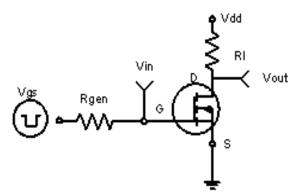
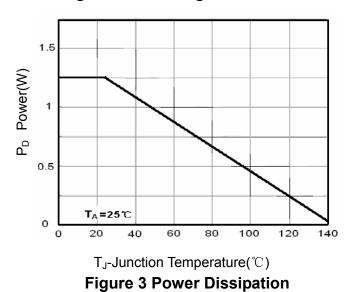
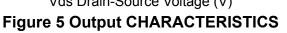


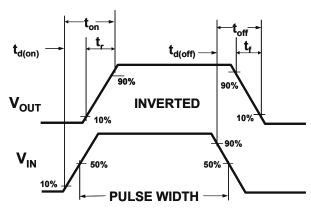
Figure 1:Switching Test Circuit



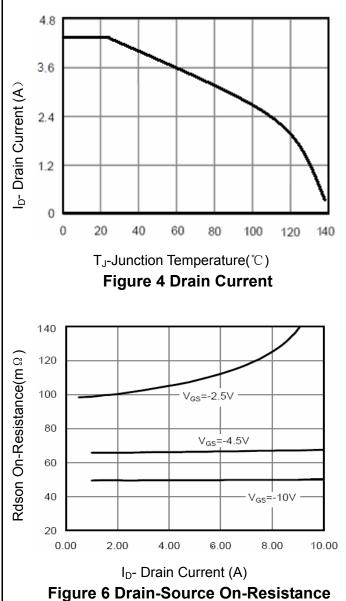
20 -5V 10V-4.5V 15 -4V 10 -3.5V 5 V_{GS}=-3V 0 0.00 1.00 2.00 3.00 4.00 5.00 Vds Drain-Source Voltage (V)

I_D- Drain Current (A)



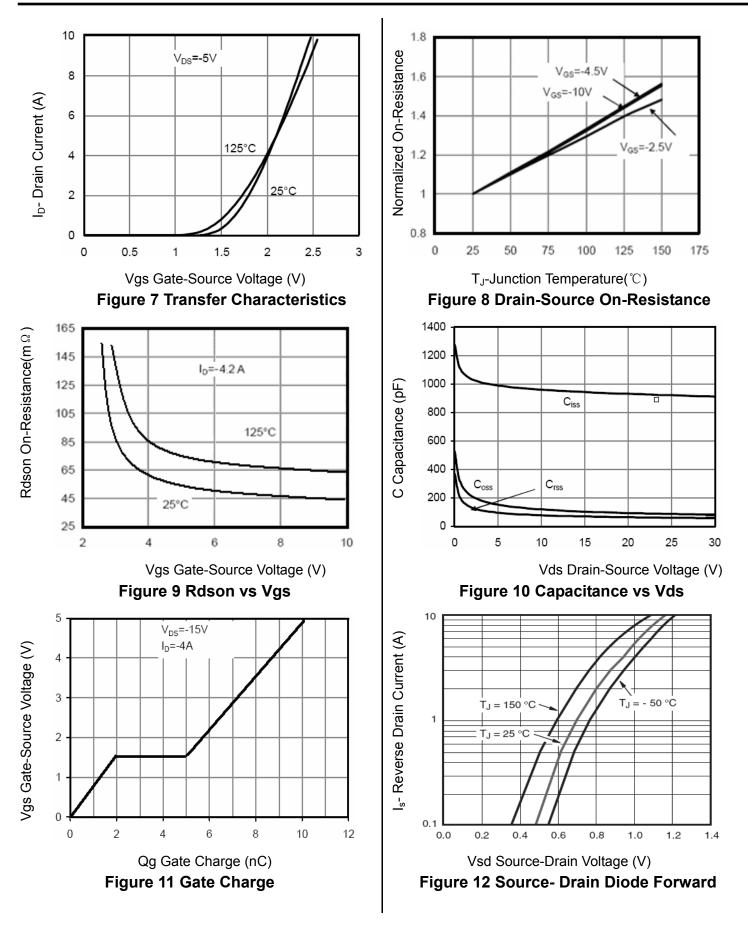






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HM6401



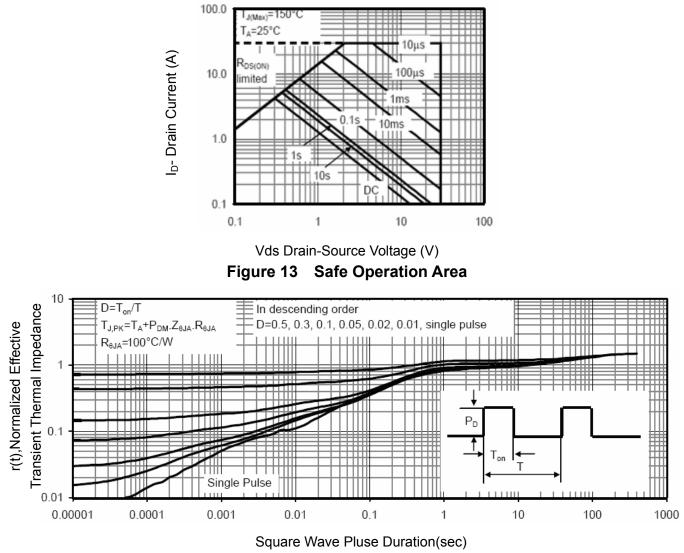
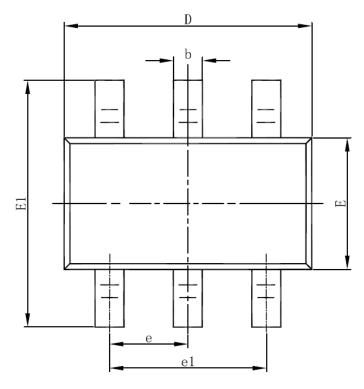
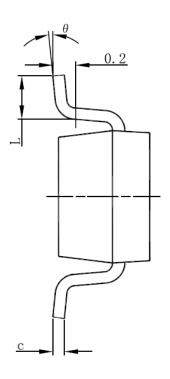
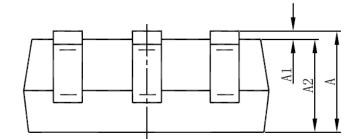


Figure 14 Normalized Maximum Transient Thermal Impedance









| Sumbal | Dimensions Ir | n Millimeters | Dimensions | s In Inches | |
|--------|---------------|---------------|------------|-------------|--|
| Symbol | Min | Max | Min | Max | |
| A | 1.050 | 1.250 | 0.041 | 0.049 | |
| A1 | 0.000 | 0.100 | 0.000 | 0.004 | |
| A2 | 1.050 | 1.150 | 0.041 | 0.045 | |
| b | 0.300 | 0.500 | 0.012 | 0.020 | |
| С | 0.100 | 0.200 | 0.004 | 0.008 | |
| D | 2.820 | 3.020 | 0.111 | 0.119 | |
| E | 1.500 | 1.700 | 0.059 | 0.067 | |
| E1 | 2.650 | 2.950 | 0.104 | 0.116 | |
| е | 0.950 | (BSC) | 0.037(BSC) | | |
| e1 | 1.800 | 2.000 | 0.071 | 0.079 | |
| L | 0.300 | 0.600 | 0.012 | 0.024 | |
| θ | 0° | 8° | 0° | 8° | |

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